## VIBRATIONAL SPECTRA AND CALCULATION OF THE NORMAL VIBRATIONS

OF 1,3-DIMETHYL-1,1,3,3-TETRACHLORODISILOXANE

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The vibrational spectra of 1,3-dimethyl-1,1,3,3-tetrachlorodisiloxane (DMTChDS) were obtained in [1] where the  $v(SiO)_s$  and  $v(SiO)_{as}$  bands were identified. No calculation of the frequencies and forms of the normal vibrations was carried out.

We have recorded the IR spectra of DMTChDS in the gaseous, liquid, and crystalline states and the Raman spectra in the liquid and crystalline states (Fig. 1). The frequencies and forms of the normal vibrations of this molecule have been calculated in order to provide a more reliable interpretation of the vibrational spectra. On account of the lack of data concerning the geometry of this molecule, data on hexachlorodisiloxane (HChDS) and hexamethyldisiloxane (HMDS) from [2, 3] were employed. The following parameters were used: RSiO 1.60Å, R<sub>SiC</sub> 1.88 Å, R<sub>SiCl</sub> 2.01 Å, R<sub>CH</sub> 1.09 Å, SiOSi 146°. The angles at the Si atoms were assumed to be tetrahedral. Retarded internal rotation around the Si-O bonds is possible in DMTChDS as a result of which this molecule can exist in the form of several conformers of  $C_1$ ,  $C_5$ ,  $C_2$ , and C2v symmetry. In carrying out the calculations it was assumed that one of the SiCl or SiC bonds of the CH<sub>3</sub>Cl<sub>2</sub>Si- groups lies on the SiOSi plane in a trans-position with respect to the SiO bond (Fig. 2) although in [2] it was concluded that there is some deviation from the planar structure of the trans-chain in HChDS. We carried out calculations for all four conformers using the one and the same force constant matrix which was set up using data on the force fields obtained in [4] for HChDS and HMDS. No additional refinement of the force field was carried out. The results of the calculations are shown in Table 1. The calculation enabled one to assign the experimental frequencies using the calculated forms of the vibrations. There is no doubt concerning the assignment of the frequencies of 2990 and 2918  $\rm cm^{-1}$ to the  $v(CH)_{as}$  and  $v(CH)_{s}$  valence vibrations respectively and the frequencies of 1405 and 1270 cm<sup>-1</sup> to the  $\delta(CH_3)_{aS}$  and  $\delta(CH_3)_S$  deformation vibrations. The absorption bands in the 760-850 cm<sup>-1</sup> region are assigned to  $\rho(CH_3)$  and, moreover, the vibration with a frequency at around 800 cm<sup>-1</sup> is very strongly mixed with  $v(SiO)_s$ . The antisymmetric  $v(SiO)_{as}$  vibration appears in the spectrum as a strong broad band the position of which varies somewhat upon passing from the liquid to the crystal (1095 cm<sup>-1</sup> in the liquid and 1145 cm<sup>-1</sup> in the crystal) which may be associated with an increase in the SiOSi angle in the crystal in comparison with this angle in the liquid [5-7]. Two frequencies, 680 and 645 cm<sup>-1</sup>, may be assigned to the  $v(SiO)_S$  vibration. The first only appears in the IR spectrum as a very weak band which is most probably a combination frequency or an overtone and it is therefore more reasonable to assign the weak band at 645 cm<sup>-1</sup> in the IR and Raman spectra to  $v(SiO)_{s}$ . It is partially polarized in the Raman spectrum. The weak, depolarized band in the Raman spectrum at 755 cm<sup>-1</sup> is assigned to the v(SiC) valence vibration. The assignment of the valence vibrations of the SiCl<sub>2</sub> groups, the vibrational frequencies of which are shown in Table 1, also does not present any significant difficulty. The assignment of the deformation vibrations of the CHaClaSifragment is considerably more difficult. These vibrations are very strongly mixed with one another and any specific assignments can only be made provisionally (Table 1).

Comparison of the IR and Raman spectra of DMTChDS in the various different states of aggregation shows that significant changes are observed in the region of the skeletal and deformation vibrations of the  $CH_3Cl_2Si-$  spinning top.

For instance, the band at 232 cm<sup>-1</sup> which is strong in the Raman spectrum of the liquid becomes weak in the Raman spectrum of the crystal. The complex band at 340 cm<sup>-1</sup> with a shoulder on the low-frequency side in the Raman spectrum of the liquid has a symmetric contour with a maximum at 325 cm<sup>-1</sup> in the spectrum of the crystal. In the IR spectrum of the crystal a doublet is observed at 325 and 319 cm<sup>-1</sup> instead of the band at 340 cm<sup>-1</sup>. There is a sig-

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Fig. 1. IR spectra (a) and Raman spectra (b) of DMTChDS: 1) gas, 2) liquid, 3) crystal.

nificant decrease in the intensity of the line at 145 cm<sup>-1</sup> and the bands associated with the  $v(SiCl_2)$  vibrations are shifted to lower frequencies in the spectrum of the crystal as compared with that of the liquid. All these changes, including the shift of the band due to the  $v(SiO)_{as}$  valence vibration can hardly be explained unless there is an increase in the SiOSi angle. Apparently, the changes indicated above are associated with a change in the conformational structure.

Apart from the investigation of the vibrational spectra in the various different phase states, we also studied the temperature dependence of the spectra within the limits of a single phase. The investigation were carried out over the following temperature ranges:

		Experiment				Calculation		
Raman			IR		No	conformer, frequ	uency $(cm^{-1})^*$ ,	Provisional
liquid	crysta1	gas	liquid	crysta1	NO.	calculation ban	d enérgy <sup>†</sup>	assignment
2985 m, <i>dp</i> 2918 s <i>p</i>	2982 m 2912 s	2990 W. 2915 W.	2990 W 2918 W	2980 m 2915 w	5,6	2969 CH 2923 CH	Name	$\gamma$ (CH) $_{as}$ $\gamma$ (CH) $_{s}$
1406 w <i>dp</i> 1270 vw <i>p</i>	1401 w	1410 vw 1410 vw 1275 s	1430 vw 1405 w 1270 s	1440 W 1390 W 1265 vs	11,12	1272 HCH		о (СН3) <i>а s</i> δ (СН3) <sub>s</sub>
835 <b>w</b>	832 W	1155 sh 1110 vs 820 sh	1095 vs 835 sh	1145 vs 828 w		1118 SiO 787 SiCH		Combination Combination v (SiO) <sub>as</sub> p (CH <sub>3</sub> )
773 w - pp	771 w	800 s	800 vs 775 w	290 vs 790 vs	291	760 SICH 760 SICH		ρ (CH <sub>3</sub> ) ρ (CH <sub>3</sub> )
756 vw dp		750 m	. 754 vw	752 m	~ 81	754 SICH 725 SIC 705 SIC		p (CH <sub>3</sub> ) v (SiC) v (SiC)
644 vw. dp		682 vw 645 vw	680 vw 645 vw	682 'yw 645 vw	50	683 SiO		v (SiO) <sub>s</sub>
562 w dp	625 vw 554 w	580 s	570s	555 s	22	607 SICI		v (SiCl <sub>2</sub> ) <sub>ds</sub> v (SiCl <sub>2</sub> ) <u>,</u>
489 VW.	100 K	490 m	489 m	4798	23	493 SiCl	73 61.7	$\tilde{v}(\text{SiCI}_{2})_{s}$
400 VW	405 sh			M (1771	7 L J C	C <sub>2</sub> 472 SiCl	C <sub>2</sub> v 458 CISIO	
340 W dn	325	340 W	340 m	296)	Q JQ	$C_1 = 0.2 CISIO$ $C_2 = 372 CISIO$ $C_2 = 0.0000$	C <sub>2</sub> <sup>v</sup> 594 CISIO C <sub>2</sub> <sup>v</sup> 431 SiCI	6 (USIU)
1 5 5		2	THT 040	319) ms	07	C <sub>2</sub> 363 CISIO C <sub>2</sub> 343 CISIO	$C_{2v}$ 380 CISIO	(UISIU) 0
					28	$\begin{bmatrix} 256 \ \tau CH_3 \\ C_1 \ 247 \ \tau CH_3 \\ 248 \ CISIO \end{bmatrix}$	Cs 242 CISIO	τCH3 δ (CISIO)
232 m dp	238				29	C <sub>1</sub> 240 TCH <sub>3</sub> C <sub>1</sub> 240 TCH <sub>3</sub>	C <sub>s</sub> 234 CISiO	ρ (SiCl₂)
					30	C <sub>1</sub> 219 TCH <sub>3</sub>	Cs 230 TCH3 Cs 230 TCH3	τCH3
					31 32	$c_1$ 212 CISIC	C <sub>s</sub> 219 CISiC	δ (CISiC) δ (SiCl2)
176 m dp 176 m dp	200 187				34 34 34	C <sub>2</sub> 214 CISICI 200 CISICI C. 174 CISIO	$C_{2\sigma}$ 218 CISIC	δ (SiCl <sub>2</sub> )
145 vs <i>dp</i>	144	•			33	$\begin{bmatrix} C_2 & 176 & CISIO \\ 151 & CISIO \\ 151 & CISIO \end{bmatrix}$	C2v 170 CSIO	n (SiCla)
					30	$C_1$ 139 CISIO $C_2$ 133 CISIO	C <sub>s</sub> 143 CISiO C <sub>s</sub> , 146 CISiO	
					39 38 39	65 SiOSi 24 TSiO 6 TSiO	1 1 2 3	δ (SiOSi) τ (SiO) <sub>as</sub> τ (SiO)
	_				39	6 TSIO		

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\*Frequencies which according to the calculation do not differ by more than ±5 cm<sup>-1</sup> for the different con-formers at the maximum value of the calculated band energy for the one and the same internal coordinate are given once without indicating the conformer. +The coordinate with the maximum value of the calculated band energy is indicated.



Fig. 2. The DMTChDS conformer with  $C_{\rm 2V}$  symmetry.

100-20°C in the case of the gas (IR), 20 to -20°C for the liquid, and -25 to -140°C for the crystal (Raman) and down to -190°C (IR). No substantial changes in the spectra were noted during this work.

Deformation vibrations are the most sensitive to rotational isomerism. Calculation showed that this is also observed in the case of the DMTChDS molecule. When this occurs, vibrations which are similar in form may differ in frequency while vibrations of different forms occurring in different conformers may have very similar frequencies. It is therefore impossible to arrive at an unambiguous judgement concerning a change in the conformation structure of DMTChDS from a comparison of the spectra for the various different states of aggregation even if such a change does occur.

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